

View Online at <https://aerobasegroup.com/nsn/5961-01-521-1582>

**Inclosure Material:**

Metal all transistor

**Overall Height:**

0.350 inches all transistor

**Overall Diameter:**

0.875 inches all transistor

**Function For Which Designed:**

Amplifier

**Mounting Facility Quantity:**

2 all transistor

**Joint Electronic Device Engineering Council/jedec/case Outline Designation:**

T0-3 all transistor

**Component Function Relationship:**

Matched

**Component Name And Quantity:**

2 transistor

**Mounting Method:**

Unthreaded hole all transistor

**Semiconductor Material:**

Silicon all transistor

**Voltage Rating In Volts Per Characteristic:**

180.0 collector to base voltage/static/emitter open all transistor

**Current Rating Per Characteristic:**

16.00 amperes zero-gate-voltage source current blank all transistor

**Power Rating Per Characteristic:**

150.0 watts small-signal input power, common-collector all transistor

**Maximum Operating Temperature Per Measurement Point:**

150.0 degrees celsius junction all transistor

**Terminal Type And Quantity:**

2 pin all transistor

**Shelf Life:**

N/a

**Unit Of Measure:**

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**Demilitarization:**

No

**Fiig:**

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